	Wald		of Engineering						
		,	2024-25	- /					
			Information						
Program	me	B.Tech. (Electro	nics Engineering)						
Class, Semester Final Year B. Tech., Sem VII									
Course C		6EN401							
Course N		Real Time Opera	ating System						
	Requisites:		Embedded System I	Design					
Desired 1	toquisites:	o programming,	Zinocaaca System I	2031811					
Tea	aching Scheme		Examination Scheme (Marks)						
Lecture	3 Hrs/week	MSE	ISE	ESE	Total				
Tutorial	- Ins, week	30	20	50	100				
Tutoriai		30	Credi		100				
			Creu	1100 · J					
		Course	e Objectives						
	To make students for			nuv/Embaddad Linu	v operating				
1	To make students far system.	ımaı witti ilistaliati	ion and use of the L1	nux/ Embedded Linu	a operating				
2	To give exposure for	Embedded Linux b	poards as per the ind	ustry trends					
3	To explain /demonstr								
4	To illustrate/demonst	rate how to design	of applications using	g RTOS.(uCOS-II)					
	Course	Outcomes (CO) v	vith Bloom's Taxon	omv Level					
At the end	d of the course, the stu								
CO1	Illustrate various OS RTOS	Linux commands,	Embedded Linux B	oard and concepts of	Understand				
CO2	Write program/ prob RTOS	em/ situation by ap	oplying the knowledg	ge acquired in Linux/	Apply				
CO3	Design the tasks and multitasking based (I			e RTOS services for	Create				
Module		Module	Contents		Hours				
I		Types of OS, Comp Linux architecture, figuration of Linux	Linux Kernel, File S x, Basic commands of		7				
II	Introduction to Embedded Linux: Embedded Linux introduction, Why Embedded Linux? Linux vs. Embedded Linux, Components of Embedded Linux Systems, , Embedded Linux Boot flow Process, Embedded Linux Boards- Raspberry Pi / Beagle Bone, Raspberry Pi / Beagle Bone - OS installation and configuration, Facilities in Embedded Linux Poords used in Industry (Market								
III	Boards used in Industry/Market Introduction to Real-time OS and Real Time system contents: RTOS Introduction, Foreground/Background Systems, Pre-emptive and Non-Pre-emptive Kernels, Priority inversion, Deadlock Task Management in RTOS:								
IV	Task structure, RTO transitions. Creating applications	S initialization, Ta and deleting a task,	, Task priority, Case	and task state studies of task-based	7				
V	Time and Event ma Clock tick, delaying study of application	a task, resuming th	e delayed task, getti	ng system time, case	7				

VI	Intertask Communication in RTOS: Need of Intertask communication, Semaphore, Mailbox, Queues in RTOS. Internals of RTOS for managing tasks and Intertask communication, Case study of RTOSapplications.					
	Textbooks					
1	Chris Simmonds, "Mastering Embedded Linux Programming", Second Edition.					
2	Jean J. Labrosse, "MicroC OS II: The Real Time Kernel", CMP books publication ISBN: 978-1578201037					
3	Chowdary Venkateswara Amazon, "Simple Real-time Operating System: A Kernel,", ISBN: 978-1425117825					
4	Qing Li, Caroline Yao Elsevier "Real-Time Concepts for Embedded Systems," ISBN: 978-1578201242					
	References					
1	https://www.engineersgarage.com/embedded-linux-tutorial-basics/					
2	"Exploring Raspberry Pi: Interfacing to the Real World with Embedded Linux" Derek Molloy	first Edition,				
3	https://freertos.org/Documentation/161204_Mastering_the_FreeRTOS_Real_Time A_Hands-On_Tutorial_Guide.pdf	e Kernel,				
4	www.micrium.com for uCOS-II related documents, tutorials, downloads.					
	Hackel I in ba					
1	Useful Links					
1	https://www.linux.org/					
2	www.nxp.com for processor specific documents.					
3	www.NPTEL.org for OS and RTOS related video courses					

	CO-PO Mapping														
				I	Progra	mme C	outcom	es (PO)				PS	PSO	
	1	2	3	4	5	6	7	8	9	10	11	12	1	2	
CO1	3														
CO2		3												2	
CO3		2									2				
CO4															

Assessment

The assessment is based on MSE, ISE and ESE.

MSE shall be typically on modules 1 to 3.

ISE shall be taken throughout the semester in the form of teacher's assessment. Mode of assessment can be field visit, assignments etc. and is expected to map at least one higher order PO.

ESE shall be on all modules with around 40% weightage on modules 1 to 3 and 60% weightage on modules 4 to 6.

		Walc		of Engineering, Autonomous Institute)					
	AY 2024-25								
				Information					
Progra	amme		B.Tech. (Electron						
	Semester		Final Year B. Tec						
	e Code		6EN402	, 2011 12					
Cours	e Name		Microwave Com	nunication Engineeri	ng				
Desire	ed Requisi	tes:	Communication I		<u>. </u>				
	<u>-</u>								
	Teaching	Scheme		Examination Sch	neme (Marks)				
Lectur	re	3 Hrs/week	MSE	ISE	ESE	Total			
Tutori	ial	-	30	20	50	100			
				Credit	s: 3				
			Course	Objectives					
1				erlying microwave d					
2					ss the losses associate				
3	To instill	knowledge on t	he properties of var	rious microwave con	ponents				
4	To deal v		•	microwave measurer	•				
				ith Bloom's Taxono	my Level				
	At the end of the course, the students will be able to, CO1 Classify the microwave frequencies and the waveguides that are used application								
CO1					* *	II			
CO2	O2 Examine the active & passive microwave devices & components used in Microwave communication systems								
CO3	1	•	and working of wave frequencies	the various tubes	or sources for the	IV			
CO4	Measure	the various mici	owave parameter u	ising analytical treatr	nent	V			
Modu	ıle		Module	Contents		Hours			
	Micr	owave Fundam	entals and Electro	magnetic field The	ory:				
T	Micro	owave regions a	and band designati	5					
ı					on motion in electric,				
	magn	etic and electror	nagnetic field, elec	tromagnetic plane wa	aves				
II Microwave Waveg Rectangular and cir power losses in war Microwave passive attenuators, phase Matrix Parameters of matrix for H-plane			alar waveguide, TE guide, excitation romponents—Tee julifters, bends, twis microwave network	8					
III	Microwave Tubes: Limitations of conventional tubes, O and M type classification of microwavetubes, re-entrant cavity, velocity modulation. Types of Tubes, Two cavity Klystron, Reflex Klystron, traveling wave tube amplifier, Magnetron								
IV	Tunn TRA		ode, Gunn diode,		ode, IMPATT diode, id state ruby laser,	7			

V	Microwave Measurements: Measurement devices: Slotted line, Tunable detector, VSWR meter, Power Meter. V S-parameter measurement, frequency measurements, Power measurement Attenuation measurement, Phase shift measurement, VSWR measurement, Impedance measurement, Q of cavity resonator measurement Microwave Strip Lines and Antenna:						
VI	_						
	Textbooks						
1	Pozar, D.M., "Microwave Engineering", 4th Edition, 2011, Wiley (ISBSN - 9781118213636)						
2	Robert E. Collin, John Wiley & Sons, FOUNDATIONS FOR MICROWAVE ENGINEERING, 2ND ED,2007, (ISBN: 8126515287)						
3	Gustrau, F, RF and Microwave Engineering: Fundamentals of Wireless Communications, 2012, Wiley, ISBN - 9781118349571						
	References						
1	Gottapu Sasibhushana Rao, "Microwave and Radar Engineering", 2014, Pearson India, (ISBN: 9789332540637)	n Education					
2	Das, A., and Das, S.K, "Microwave Engineering", McGraw-Hill, 2000, (ISBN - 9780074635773)						
3	S Vasuki and D Helena Margaret, R Rajeswari, "Microwave Engineering", McGraw Hill Education (India) Private Limited, ISBN 933921949X, 9789339219499						
	Useful Links						
1	https://onlinecourses.nptel.ac.in/noc20_ee91/preview						

	CO-PO Mapping												
		Programme Outcomes (PO) PSO									SO		
	1	1 2 3 4 5 6 7 8 9 10 11 12 1 2											
CO1	3												
CO2				3									
CO3				3									
CO4				3									

The strength of mapping is to be written as 1: Low, 2: Medium, 3: High

Each CO of the course must map to at least one PO.

Assessment

The assessment is based on MSE, ISE and ESE.

MSE shall be typically on modules 1 to 3.

ISE shall be taken throughout the semester in the form of teacher's assessment. Mode of assessment can be field visit, assignments etc. and is expected to map at least one higher order PO.

ESE shall be on all modules with around 40% weightage on modules 1 to 3 and 60% weightage on modules 4 to 6.

Walchand College of Engineering, Sangli (Government Aided Autonomous Institute) AY 2024-25 **Course Information** B.Tech. (Electronics Engineering) **Programme** Final Year B. Tech., Sem VII Class, Semester 6FN451 Course Code **Course Name** Real Time Operating System Lab **Desired Requisites:** Theory/Lab Courses with C programming, Microcontroller Peripherals and Interfacing, Embedded System Design. **Teaching Scheme Examination Scheme (Marks)** Practical 2 Hrs/ Week Lab ESE LA1 LA2 Total Interaction 30 100 30 40 Credits: 1 **Course Objectives** To learn system Architecture, configuration and Programming for Embedded Linux Based System. 1 2 To facilitate students to gain practical experience of RTOS and services provided by it. 3 To help students to co-relate the RTOS theory with the RTOS implementation. To provide exposure to industry applications and facilitate for writing applications using Linux and 4 RTOS. Course Outcomes (CO) with Bloom's Taxonomy Level At the end of the course, the students will be able to, Installation of OS Process and write programs / scripts for Embedded Linux Board. CO₁ Apply Verify the RTOS fundamentals, through illustrative programs and demonstrate usage Analyze CO₂ of task, time, and event management, Intertask communication using a simulator. (Programming skill, Modern Tools) Implement a given logic as an RTOS based application. Create document of the same Create

List of Experiments / Lab Activities/Topics

and demonstrate using simulation tools. (Programming skill, Independent and

List of Lab Activities:

CO₃

- 1. Experiments to revise an Embedded System Design
- 2. Experiment to study Linux distribution installation, configuration and basic commands of it.
- 3. Experiment to study configuration for an Embedded Linux Board.
- 4. Experiment to access GPIO of an Embedded Linux Board to control components / devices interfaced to it.
- 5. Demonstration of RTOS based application in keil micro vision
- 6. Writing of RTOS based application.

teamwork, Modern Tools)

- 7. Finding the type of kernel for a given RTOS (Pre-emptive or Non-pre-emptive)
- 8. Semaphore for managing shared resource and task synchronization
- 9. Demonstration of Clock tick and its effect of event timing in RTOS based systems.
- 10. Semaphore for event synchronization
- 11. Using mailbox facility in RTOS
- 12. Using queue facility in RTOS
- 13. Avoiding deadlock in RTOS

	Textbooks							
1	Chris Simmonds, "Mastering Embedded Linux Programming", Second Edition.							
2	Derek Molloy ,"Exploring Raspberry Pi: Interfacing to the Real World with Embedded Linux" first Edition,							
3	Jean J. Labrosse, "MicroC OS II: The Real Time Kernel" CMP books publication ISBN: 978-1578201037							

4	RTOS Lab Manual								
	References								
1	https://www.engineersgarage.com/embedded-linux-tutorial-basics/								
2	www.micrium.com for uCOS-II related documents, tutorials, downloads.								
3	https://www.freertos.org/Documentation/RTOS_book.html								
4	Everything You Need to Know about RTOS (pdf book) by Silabs								
	Useful Links								
1	https://www.linux.org/								
2	https://www.raspberrypi.org/								
3	www.highintegritysystems.com/rtos for RTOS tutorials								
4	https://www.youtube.com/watch?v=ECEvUEkSSLg for videos by Renesas Inc.								

	CO-PO Mapping												
	Programme Outcomes (PO)									PS	PSO		
	1 2 3 4 5 6 7 8 9 10 11 12								1	2			
CO1		3											
CO2			3									2	
CO3				2					2				2

Assessment

There are three components of lab assessment, LA1, LA2 and Lab ESE.

IMP: Lab ESE is a separate head of passing.(min 40 %), LA1+LA2 should be min 40%

Assessment	Based on	Conducted by	Typical Schedule	Marks
LA1	Lab activities, attendance, journal	Lab Course Faculty	During Week 1 to Week 8 Marks Submission at the end of Week 8	30
LA2	Lab activities, attendance, journal	Lab Course Faculty	During Week 9 to Week 16 Marks Submission at the end of Week 16	30
Lab ESE	Lab activities, journal/ performance	Lab Course Faculty and External Examiner as applicable	During Week 18 to Week 19 Marks Submission at the end of Week 19	40

Walchand College of Engineering, Sangli

(Government Aided Autonomous Institute)

AY 2024-25

Course Information							
Programme B.Tech. (Electronics Engineering)							
Class, Semester Final Year B. Tech., Sem VII							
Course Code	6EN452						
Course Name	Microwave Communication Engineering Lab						
Desired Requisites:	Communication						

Teaching	Scheme		Examination S	Scheme (Marks)					
Practical 2 Hrs/ Week LA1 LA2 Lab ESE Total									
Interaction	-	30	30	40	100				
		Credits: 1							

	Course Objectives					
1	To understand the theoretical principles underlying microwave devices and networks					
2	To introduce the various types of transmission lines and to discuss the losses associate					
3	To instill knowledge on the properties of various microwave components					
4	To deal with the microwave generation and microwave measurement techniques					
	Course Outcomes (CO) with Bloom's Taxonomy Level					
At the	end of the course, the students will be able to,					
CO1	Classify the microwave frequencies and the waveguides that are used application	II				
CO2	Examine the active & passive microwave devices & components used in Microwave communication systems	IV				
CO3	Analyze the operation and working of the various tubes or sources for the transmission of the microwave frequencies	IV				
CO4	Measure the various microwave parameter using analytical treatment	V				

List of Experiments / Lab Activities/Topics

List of Lab Activities:

List of Experiments:

- 1. Study of Microwave components and equipment
- 2. Study of V-I Characteristics of Gunn Diode
- 3. Reflex Klystron as source and plot its various modes
- 4. Verification of port characteristics of E-plane tee, H-plane tee & Damp; Magic tree
- 5. Verification of port characteristics of Microwave Circulator and isolator, calculation of insertion loss and isolation loss
- 6. Verification of port characteristics of Directional coupler, calculation of coupling factor, insertion loss and directivity.
- 7. Power pattern of Horn Antenna
- 8. Power Patterns of different Antenna like Dipole, Yagi etc.
- 9. Study of slotted section with probe carriage. Measure the VSWR for various values of terminating impedances (open/short/matched termination).
- 10. To test and verify Microwave Integrated Circuits using Microstrip trainer kit and finds parameters, and plot the frequency response.

Textbooks								
1	Microwave Engineering, 4th Edition, Pozar, D.M., 2011, Wiley (ISBSN - 9781118213636)							
2	FOUNDATIONS FOR MICROWAVE ENGINEERING, 2ND ED, By Robert E. Collin, John Wiley & Sons, 2007, (ISBN: 8126515287)							
3	RF and Microwave Engineering: Fundamentals of Wireless Communications, Gustrau, F, 2012, Wiley, ISBN - 9781118349571							
	2012, Wiley, ISBN 9701110349371							

References														
1	Microwave and Radar Engineering, By Gottapu Sasibhushana Rao · 2014, Pearson Education India, (ISBN: 9789332540637)													
2		Microwave Engineering, Das, A., and Das, S.K., McGraw-Hill, 2000, (ISBN - 9780074635773)												
3										Rajesv 921949		IcGraw	Hill	
						Usefu	l Links							
1	https:/	//online	courses	.nptel.	ac.in/no	oc20_ee	e91/pre	view						
						CO-P	O Map	ping						
	Programme Outcomes (PO)										PS	50		
	1	2	3	4	5	6	7	8	9	10	11	12	1	2
CO1	3													

Assessment

There are three components of lab assessment, LA1, LA2 and Lab ESE.

3

3

CO₂

CO3

IMP: Lab ESE is a separate head of passing.(min 40 %), LA1+LA2 should be min 40%

Assessment	Based on	Conducted by	Typical Schedule	Marks
LA1	Lab activities, attendance, journal	Lab Course Faculty	During Week 1 to Week 8 Marks Submission at the end of Week 8	30
LA2	Lab activities, attendance, journal	Lab Course Faculty	During Week 9 to Week 16 Marks Submission at the end of Week 16	30
Lab ESE	Lab activities, journal/ performance	Lab Course Faculty and External Examiner as applicable	During Week 18 to Week 19 Marks Submission at the end of Week 19	40

Walchand College of Engineering, Sangli

(Government Aided Autonomous Institute)

AY 2024-25

Course Information							
Programme B. Tech. (Electronics Engineering)							
Class, Semester	Final Year B. Tech. Sem. VII						
Course Code	6EN491						
Course Name	Project-I						
Desired Requisites:	Mini-Project						

Teachin	g Scheme	Examination Scheme (Marks)								
Practical 6 Hrs/Week		LA1	LA2	Lab ESE	Total					
Interaction -		30	30	40	100					
		Credits: 3								

Course	Ohi	iootivos
Course	OD	iecuves

- **Explain** to survey and study the published literature on the assigned/ selected topic. The topicmay be chosen from the problem assigned by the industry. The chosen topic may provide a solution to 1 the electronics industry problem/ solution to societal needs.
 - **Explain** the use of methods/ methodology/ procedures/ software tools to carry out preliminary Analysis/ Modelling/ Simulation/ Experiment/ Design. It is expected to find out the feasibility of 2 the project.
- Illustrate the guidelines to write and organize the project report based on the study conducted for 3 presentation to the department.

Course Outcomes (CO) with Bloom's Taxonomy Level

At the	At the end of the course, the students will be able to,						
CO1	Explain the purpose of the project and conceptual idea behind the project.	Understand					
CO2	Analyze the journal/ conference/ research papers/ magazine articles and present the comparative study of similar work done by others.	Analyze					
СОЗ	Propose a research problem/ problem undertaken as project-work and present it in a clear and distinct manner through different design techniques which meets the desired objectives of the project-work.	Create					
CO4	Prepare and Organize written report on the study conducted/part of project-work (simulations/ technical design) completed for presentation before the department committee.	Apply					

List of Experiments / Lab Activities/ Topics

The objective of Project-I is to enable the student to take up investigative study in the broad field of Electronics Engineering, either fully theoretical/practical or involving both theoretical and practical work to be assigned by the Department on an individual basis or three/five students in a group, under the guidance of a Supervisor from the Department alone or jointly with a Supervisor/ Mentor from Industry. This is expected to provide a good initiation for the student(s) in R&D work.

The Projects may be chosen from the following areas/domains, but not limited to:

- Embedded Systems/ VLSI Design
- **Electronic Communication Systems**
- **Biomedical Electronics**
- Power Electronics/ Electric Vehicles
- Robotics and Mechatronic Systems
- Artificial Intelligence and Machine Learning
- Applications of Electronics to Agriculture

Assessment: A demonstration and oral examination on the Project-I shall be conducted at the end of the semester.

	Text Books
1	Journal/ Conference papers/ Magazine Articles/ Handbooks with reference to topic selected for the project-work.

	References							
1	Journal/ Conference papers/ Magazine Articles/ Handbooks with reference to topic selected for							
1	the project-work.							
	Useful Links							
1	https://ieeexplore.ieee.org							
2	https://www.sciencedirect.com							
3	https://www.elsevier.com							

CO-PO Mapping														
		Programme Outcomes (PO)											PSO	
	1	2	3	4	5	6	7	8	9	10	11	12	1	2
CO1	3					3	2			2			2	2
CO2		3		3									3	3
CO3			3		2								3	3
CO4								2	3	3	3	2	2	2

Assessment

There are three components of lab assessment, LA1, LA2 and Lab ESE.

IMP: Lab ESE is a separate head of passing (min 40 %). LA1, LA2 together is treated as In-Semester Evaluation, LA1+LA2 should be min 40%.

Assessment	Based on	Conducted by	Typical Schedule	Marks		
LA1	Lab activities,	activities, Lab Course During Week 1 to Week 8				
LAI	attendance, journal	Faculty	Marks Submission at the end of Week 8	30		
LA2	Lab activities,	Lab Course	During Week 9 to Week 16	30		
LAZ	attendance, journal	Faculty	Marks Submission at the end of Week 16	30		
		Lab Course	During Week 18 to Week 19			
	Lab activities,	Faculty and	Marks Submission at the end of Week 19			
Lab ESE	journal/	External		40		
	performance	Examiner as				
		applicable				

		Walc		of Engineering						
			`	l Autonomous Institut 2024-25	e)					
				Information						
D										
Progra			B.Tech. (Electron							
	Semester		Final Year B. Tec	ch., Sem VII						
	e Code		6EN411							
Cours	e Name		Professional Elec	tive V - RF Circuit	Design					
Desire	d Requisi	tes:	ECAD							
	Tasahina	Cahama		Examination S	ohomo (Morks)					
	Teaching	3 Hrs/week	MCE			Tatal				
Lectur		3 Hrs/week	MSE	ISE	ESE	Total 100				
Tutor	rial - 30 20 50 Credits: 3									
				Cred	its: 3					
				01: /						
	- T	1 1 6		Objectives						
1					tegrated circuit designated	gn				
$\frac{2}{3}$		RF transceiver		ircuit building bloc	KS					
3	Study the			ith Bloom's Taxor	omy I ovol					
At the	end of the		ents will be able to		iomy Level					
CO1		·		ith transmission lin	<u> </u>	l II				
$\frac{\text{CO1}}{\text{CO2}}$				ransistor for RF IC		IV				
$\frac{\text{CO3}}{\text{CO3}}$				implifier and switch		VI				
				F						
Modu	ıle		Module	Contents		Hours				
		ed Elements:								
	TD. 1		Flactromagnetics	Warra Equation						
					Skin Depth, Sur					
I	Imped	lance, Fundame	entals of Lumped E	Elements, Modeling	of Lumped Eleme	nts, 7				
Ι	Imped Induc	lance, Fundame tors, Inductor	entals of Lumped E Configurations,	Elements, Modeling	_ ·	nts, 7				
I	Imped Induc Capad	lance, Fundame tors, Inductor citors, Lumped	entals of Lumped E Configurations, Element Resistors	Elements, Modeling	of Lumped Eleme	nts, 7				
	Imped Induc Capad Tran	lance, Fundame tors, Inductor citors, Lumped I smission Lines	entals of Lumped E Configurations, Element Resistors	Elements, Modeling Loss in Induct	g of Lumped Eleme ors, Lumped-Elem	nts, 7				
I	Imped Induc Capad Tran Printe	lance, Fundame tors, Inductor citors, Lumped l smission Lines d-Circuit Trans	entals of Lumped E Configurations, Element Resistors : emission Lines, Tra	Elements, Modeling Loss in Induct ansmissionLines in	g of Lumped Eleme ors, Lumped-Elen RFICs, Multi-Cond	nts, 7 nent 7				
	Imped Induc Capad Tran Printe Trans	lance, Fundame tors, Inductor citors, Lumped I smission Lines d-Circuit Trans mission Lines F	entals of Lumped E Configurations, Element Resistors : emission Lines, Tra RESONATORS, Fu	Elements, Modeling Loss in Induct ansmissionLines in undamentals of Res	g of Lumped Eleme ors, Lumped-Elem	nts, 7 nent 7 uctor 7 ctor,				
	Imped Induc Capad Trans Printe Trans Distri Netw	lance, Fundame tors, Inductor citors, Lumped I smission Lines d-Circuit Trans mission Lines F buted Resonato orks	entals of Lumped E Configurations, Element Resistors : emission Lines, Tra RESONATORS, Furs, Impedance M	Elements, Modeling Loss in Induct ansmissionLines in undamentals of Res	g of Lumped Eleme ors, Lumped-Elen RFICs, Multi-Condi- conators, Quality Fa	nts, 7 nent 7 uctor 7 ctor,				
II	Imped Induc Capad Trans Printe Trans Distri Netw	lance, Fundame tors, Inductor sitors, Lumped lands smission Lines d-Circuit Trans mission Lines F buted Resonato orks ering Paramete	entals of Lumped E Configurations, Element Resistors : emission Lines, Tra RESONATORS, Furs, Impedance M	Loss in Induct nsmissionLines in andamentals of Resatching, Design of	g of Lumped Eleme ors, Lumped-Elen RFICs, Multi-Condi- conators, Quality Fa of Impedance-Matc	nts, 7 nent 7 nent 7 netor, ctor, ching				
	Imped Induc Capad Trans Printe Trans Distri Netw Scatt	lance, Fundame tors, Inductor sitors, Lumped I smission Lines d-Circuit Trans mission Lines I buted Resonato orks ering Parameter assive Component	entals of Lumped E Configurations, Element Resistors : emission Lines, Tra RESONATORS, Fu rs, Impedance M ers: nents, Characteristi	Loss in Induct unsmissionLines in undamentals of Resatching, Design of	g of Lumped Eleme ors, Lumped-Elen RFICs, Multi-Condi- conators, Quality Fa of Impedance-Matc	nts, 7 nent 7 nent 7 netor, ctor, ching				
II	Imped Induction Capace Trans Printe Trans Distri Netw Scatt Rf F Direc	lance, Fundame tors, Inductor citors, Lumped I smission Lines d-Circuit Trans mission Lines I buted Resonato orks ering Parameta cassive Compositional Couplers	entals of Lumped E Configurations, Element Resistors : emission Lines, Tra RESONATORS, Fu rs, Impedance M ers: nents, Characteristi , Hybrids, PowerD	Loss in Induct ansmissionLines in undamentals of Res atching, Design of ics of Multiport R ividers, Filters Desi	g of Lumped Eleme ors, Lumped-Elen RFICs, Multi-Condi- conators, Quality Fa of Impedance-Matc	nts, 7 nent 7 nent 7 netor, ctor, ching				
III	Imped Inductor Capace Trans Printe Trans Distri Netw Scatt Rf F Direct Fund	lance, Fundame tors, Inductor citors, Lumped I smission Lines d-Circuit Trans mission Lines I buted Resonato orks ering Paramet assive Comportional Couplers amentals Of C	entals of Lumped E Configurations, Element Resistors: : :mission Lines, Tra RESONATORS, Furs, Impedance M ers: nents, Characteristi , Hybrids, PowerDi mos Transistors F	Loss in Induct ansmissionLines in indamentals of Resatching, Design of the control of the contr	g of Lumped Eleme ors, Lumped-Eleme RFICs, Multi-Conductors, Quality Factor Impedance-Matcher Passive Componing.	nts, 7 nent 7 nent 7 nettor, ctor, ching ents, 7				
II	Imped Inductor Capace Trans Printe Trans Distri Netw Scatt Rf F Direct Fund MOS	lance, Fundame tors, Inductor citors, Lumped I smission Lines d-Circuit Trans mission Lines F buted Resonato orks ering Paramete assive Composi- tional Couplers amentals Of Capter Basics, MC	entals of Lumped E Configurations, Element Resistors : emission Lines, Tra RESONATORS, Fu rrs, Impedance M ers: nents, Characteristi , Hybrids, PowerDi mos Transistors F DSFET Models, Im	Loss in Induct ansmissionLines in Indamentals of Reseatching, Design of Multiport Researching, Filters Design: portant MOSFET I	g of Lumped Eleme ors, Lumped-Eleme RFICs, Multi-Conductors, Quality Factor Impedance-Match Passive Componign.	nts, 7 nent 7 nent 7 netor, 7 ctor, 9 hing ents, 7 ers, 6				
III	Imped Induction Capace Trans Printe Trans Distri Netw Scatt Rf F Direct Fund MOS Varace	lance, Fundame tors, Inductor citors, Lumped I smission Lines d-Circuit Trans mission Lines I buted Resonato orks ering Paramet assive Comportional Couplers amentals Of Carter Basics, Montor Diodes, Fur	entals of Lumped E Configurations, Element Resistors : Emission Lines, Tra RESONATORS, Fu rs, Impedance M ers: hents, Characteristi Hybrids, PowerD mos Transistors F DSFET Models, Im damentals of Stabi	Lements, Modeling Loss in Induct ansmissionLines in Induct ansmissionLines in Indamentals of Reseatching, Design of the Induction of Multiport Rividers, Filters Design: portant MOSFET I lity, Determination	g of Lumped Eleme ors, Lumped-Eleme RFICs, Multi-Conductors, Quality Factor Impedance-Matcher Passive Componing.	nts, 7 nent 7 nent 7 netor, 7 ctor, 9 hing ents, 7 ers, 6				
III	Imped Induction Capace Trans Printed Trans District Network Scatt Rf F Direct Fund MOS Varace Region	lance, Fundame tors, Inductor citors, Lumped I smission Lines d-Circuit Trans mission Lines I buted Resonato orks ering Paramet assive Comportional Couplers amentals Of C FET Basics, Mo tor Diodes, Furns, Stability Co	entals of Lumped E Configurations, Element Resistors : emission Lines, Tra RESONATORS, Fu rs, Impedance M ers: nents, Characteristi Hybrids, PowerDi mos Transistors F DSFET Models, Im damentals of Stabi nsideration for N-F	Lements, Modeling Loss in Induct ansmissionLines in Induct ansmissionLines in Indamentals of Reseatching, Design of the Induction of Multiport Rividers, Filters Design: portant MOSFET I lity, Determination	g of Lumped Eleme ors, Lumped-Eleme RFICs, Multi-Conductors, Quality Factor Impedance-Match Passive Componign.	nts, 7 nent 7 nent 7 netor, 7 ctor, 9 hing ents, 7 ers, 6				
III	Imped Inductor Capace Trans Printer Trans Distri Netw Scatt Rf F Direct Fund MOS Varace Region Fund	lance, Fundame tors, Inductor citors, Lumped I smission Lines d-Circuit Trans mission Lines I buted Resonato orks ering Paramet eassive Comportional Couplers amentals Of C FET Basics, MO tor Diodes, Fundamentals of Ar	entals of Lumped E Configurations, Element Resistors : emission Lines, Tra RESONATORS, Fu rs, Impedance M ers: nents, Characteristi Hybrids, PowerDi mos Transistors F DSFET Models, Im Idamentals of Stabi Insideration for N-E Inplifier Design:	Loss in Induct Loss in Induct ansmissionLines in andamentals of Reseatching, Design of ics of Multiport R ividers, Filters Design: portant MOSFET I lity, Determination Port Circuits	g of Lumped Eleme ors, Lumped-Eleme RFICs, Multi-Conductionators, Quality Factor Impedance-Match Passive Componign.	nts, 7 nent 7 nent 7 nent 7 nent 7 nent 7 nettor, ctor, ching nents, 7 nents, 6 nent 7				
III	Imped Inductor Capace Trans Printe Trans Distri Netw Scatt Rf F Direct Fund MOS Varace Region Fund Low	lance, Fundamentors, Inductor citors, Lumped Ismission Lines and Circuit Transmission Lines Is buted Resonators are Parameter assive Comportional Couplers amentals Of Cifet Basics, Motor Diodes, Fundamentals of Arenoise Amplifications, Stability Componentals of Arenoise Amplifications, Inductor Parameter amentals of Arenoise Amplifications, Inductor Parameter amen	entals of Lumped E Configurations, Element Resistors : emission Lines, Tra RESONATORS, Fu rrs, Impedance M ers: nents, Characteristi , Hybrids, PowerDi mos Transistors F DSFET Models, Im adamentals of Stabi insideration for N-P inplifier Design: ers, Power Ampl	Loss in Induct Loss in Induct ansmissionLines in andamentals of Reseatching, Design of ics of Multiport R ividers, Filters Design: portant MOSFET I lity, Determination Port Circuits	g of Lumped Eleme ors, Lumped-Eleme RFICs, Multi-Conditionators, Quality Factor Impedance-Mater F Passive Componign. Frquencies, Paramet of Stable and Unstandard Amplifiers, Broadb	nts, 7 nent 7 nent 7 nent 7 nent 7 nent 7 nettor, ctor, ching nents, 7 nents, 6 nent 7				
III III	Imped Inductor Capace Trans Printed Trans District Network Scatt Rf F Direct Fund MOS Varace Region Fund Low Ampl Funda	lance, Fundame tors, Inductor citors, Lumped I smission Lines and Circuit Transmission Lines I buted Resonato orks ering Parameter Cassive Comportional Couplers amentals Of Castor Diodes, Furns, Stability Comportations, Stability Compositions of Arnoise Amplifications, Current Mannentals of Mi	entals of Lumped E Configurations, Element Resistors : Emission Lines, Tra RESONATORS, Fu rs, Impedance M ers: hents, Characteristi Hybrids, PowerDi mos Transistors F DSFET Models, Impedamentals of Stabi insideration for N-F hplifier Design: hers, Power Ampl Mirrors, Fundament	Loss in Induct ansmissionLines in Induct ansmissionLines in Indamentals of Reseatching, Design of Induct ics of Multiport Residues, Filters Design: portant MOSFET Induction Port Circuits ifiers, Balanced Anals of Oscillator Designs	g of Lumped Eleme ors, Lumped-Eleme RFICs, Multi-Conditionators, Quality Factor Impedance-Mater F Passive Componign. Frquencies, Paramet of Stable and Unstandard Amplifiers, Broadb	nts, 7 nent 7 nent 7 nent 7 nent 7 nettor 7 nettor, ching ents, 7 nents, 6 nble 6				
III III	Imped Inductor Capace Trans Printer Trans Distri Netw Scatt Rf F Direct Fund MOS Varace Region Fund Low Ampl Funda Mixel	lance, Fundame tors, Inductor citors, Lumped I smission Lines and Circuit Transmission Lines I buted Resonato orks ering Parameter assive Comportional Couplers amentals Of Circuit Transmission Lines I buted Resonato orks ering Parameter amentals Of Circuit Passive Comportional Couplers amentals Of Circuit Passive Amplifications, Stability Composed amentals of Amplifications, Current Mannentals of Minnentals of Minnen	entals of Lumped E Configurations, Element Resistors : emission Lines, Tra RESONATORS, Fu rs, Impedance M ers: nents, Characteristi Hybrids, PowerDe mos Transistors F DSFET Models, Im Idamentals of Stabi Insideration for N-E Inplifier Design: Iters, Power Ampl Mirrors, Fundament Exers, Mixer Types	Loss in Induct ansmissionLines in Induct ansmissionLines in Indamentals of Reseatching, Design of Induct ics of Multiport Residues, Filters Design: portant MOSFET Induction Port Circuits ifiers, Balanced Anals of Oscillator Designs	RFICs, Multi-Conditionators, Quality Faof Impedance-Mater F Passive Componign. Frquencies, Paramet of Stable and Unstate Amplifiers, Broadbesign, Phase Noise,	nts, 7 nent 7 nent 7 nent 7 nent 7 nettor 7 nettor, ching ents, 7 nents, 6 nble 6				
III III	Imped Inductor Capace Trans Printer Trans Distri Netw Scatt Rf F Direct Fund MOS Varace Region Fund Low Ampl Funda Mixer Fund	lance, Fundamentors, Inductor citors, Lumped Ismission Lines and Circuit Transmission Lines Is buted Resonators are Parameter assive Comportional Couplers amentals Of Cifet Basics, Motor Diodes, Furnas, Stability Commentals of Ar Noise Amplifications, Current Manentals of Michael Amentals of Swamentals of Swa	entals of Lumped E Configurations, Element Resistors: Emission Lines, Tra RESONATORS, Furs, Impedance M ers: Hents, Characteristic, Hybrids, PowerDimos Transistors F DSFET Models, Impedamentals of Stabilinsideration for N-Emplifier Design: Hers, Power Amplemental Mirrors, Fundamental Mirrors, Fundamental Mirrors, Fundamental Mirrors, Fundamental Mirrors, Mixer Types	Loss in Induct ansmissionLines in Induct ansmissionLines in Indamentals of Researching, Design of Induct ics of Multiport Researching, Filters Design: port Rfic Design: portant MOSFET Indicated Induction Port Circuits als of Oscillator Design of Induction Induc	RFICs, Multi-Conditionators, Quality Fasor Impedance-Mater F Passive Componign. Frquencies, Parametrof Stable and Unstablesign, Phase Noise, and Design, Samples	nts, 7 nent 7 nent 7 nent 7 nent 7 netor, ctor, ching ents, 7 ers, 6 nble and 6 ling 6				
III IV V	Imped Inductor Capace Trans Printe Trans Distri Netw Scatt Rf F Direct Fund MOS Varace Region Fund Low Ampl Funda Mixer Fund Analy	lance, Fundamentors, Inductor citors, Lumped Ismission Lines and Circuit Transmission Lines Is buted Resonato orks Parameter Parameter Cassive Compositional Couplers amentals Of Camentals of Arrons, Stability Compositional Couplers amentals of Arrons, Stability Compositional Couple amentals of Arrons amentals of Switching Stability Couple amentals of Switching Stability Couple amentals of Switching S	entals of Lumped E Configurations, Element Resistors : emission Lines, Tra RESONATORS, Fu rrs, Impedance M ers: nents, Characteristi , Hybrids, PowerDi mos Transistors F DSFET Models, Im damentals of Stabi insideration for N-F inplifier Design: ers, Power Ampl Mirrors, Fundament xers, Mixer Types vitches: g MOSFET, SPST S	Elements, Modeling Loss in Induct ansmissionLines in undamentals of Researching, Design of ics of Multiport R ividers, Filters Design: portant MOSFET I lity, Determination Port Circuits ifiers, Balanced A als of Oscillator Design, Mixer Analysis Switches, SPDT Sw	RFICs, Multi-Conditionators, Quality Fasor Impedance-Mater F Passive Componign. Frquencies, Parametrof Stable and Unstablesign, Phase Noise, and Design, Samplifiches, Ultra-Wideb	nts, 7 nent 7 nent 7 nent 7 nent 7 netor, 7 nents, 7 ents, 6 nents, 7				
II III IV	Imped Inductory Capaci Trans Printed Trans Distriction Network Scatt Rf F Direction MOS Varacted Region Funda Low Ample Funda Mixed Funda Analy Switch	lance, Fundamentors, Inductor citors, Lumped Ismission Lines and Circuit Transmission Lines and Educational Couplers amentals Of Circuit Transmission Lines are Parameter assive Comportional Couplers amentals Of Circuit Pasics, Motor Diodes, Furnas, Stability Commentals of Arminise Amplifications, Current Manentals of Minamentals of Switching amentals	entals of Lumped E Configurations, Element Resistors : Emission Lines, Tra RESONATORS, Fu rs, Impedance M ers: Hents, Characteristi Hybrids, PowerDi mos Transistors F DSFET Models, Im Idamentals of Stabi Insideration for N-F Inplifier Design: Hers, Power Ampl Mirrors, Fundament ixers, Mixer Types vitches: Hybrids Synthesis Hybrids S	Loss in Induct ansmissionLines in Induct ansmissionLines in Indamentals of Researching, Design of Induct ics of Multiport Researching, Filters Design: portant MOSFET Indicated Induction Port Circuits ifiers, Balanced Induction Induction Induction Induction Sont Richard Induction Induction Induction Induction Induction Induction Induction Induction Inductio	RFICs, Multi-Conditionators, Quality Fastive Componign. Frquencies, Parametrof Stable and Unstablesign, Phase Noise, and Design, Samplifiches, Ultra-Wideberfic Simulation, R	nts, 7 nent 7 nent 7 nent 7 nent 7 netor, 7 nents, 7 ers, 6 nable 6 and 6 ling eand				
II III IV	Imped Inductory Capace Trans Printed Trans District Network Scatt Rf F Direct Fund MOS Varace Region Fund Low Ampl Funda Mixed Fund Analy Switch	lance, Fundamentors, Inductor citors, Lumped Ismission Lines and Circuit Transmission Lines and Educational Couplers amentals Of Circuit Transmission Lines are Parameter assive Comportional Couplers amentals Of Circuit Pasics, Motor Diodes, Furnas, Stability Commentals of Arminise Amplifications, Current Manentals of Minamentals of Switching amentals	entals of Lumped E Configurations, Element Resistors : Emission Lines, Tra RESONATORS, Fu rs, Impedance M ers: Hents, Characteristi Hybrids, PowerDi mos Transistors F DSFET Models, Im Idamentals of Stabi Insideration for N-F Inplifier Design: Hers, Power Ampl Mirrors, Fundament ixers, Mixer Types vitches: Hybrids Synthesis Hybrids S	Elements, Modeling Loss in Induct ansmissionLines in undamentals of Researching, Design of ics of Multiport R ividers, Filters Design: portant MOSFET I lity, Determination Port Circuits ifiers, Balanced A als of Oscillator Design, Mixer Analysis Switches, SPDT Sw	RFICs, Multi-Conditionators, Quality Fastive Componign. Frquencies, Parametrof Stable and Unstablesign, Phase Noise, and Design, Samplifiches, Ultra-Wideberfic Simulation, R	nts, 7 nent 7 nent 7 nent 7 nent 7 netor, 7 nents, 7 ents, 6 nents, 7				

	Textbooks										
1	Radio-frequency integrated-circuit engineering / Cam Nguyen, Wiley series in microwave and optical engineering, ISBN 978-1-118-93648-1, 2015										
2	2 High-Frequency Integrated Circuits, Sorin Voinigescu, Cambridge University, ISBN-13: 978-0521873024										
	References										
1	The Design of CMOS Radio-Frequency Integrated Circuits, by Thomas H. Lee, ISBN: 978-0521835398										
2	RF Microelectronics, 2nd Edition, by Behzad Razavi, Prentice Hall, ISBN: 978-0137134731										
	· ·										
	Useful Links										
1	1 -										

	CO-PO Mapping													
		Programme Outcomes (PO) PSO												
	1	1 2 3 4 5 6 7 8 9 10 11 12											1	2
CO1				3										
CO2				3										
CO3				3										
CO4														

Assessment

The assessment is based on MSE, ISE and ESE.

MSE shall be typically on modules 1 to 3.

ISE shall be taken throughout the semester in the form of teacher's assessment. Mode of assessment can be field visit, assignments etc. and is expected to map at least one higher order PO.

ESE shall be on all modules with around 40% weightage on modules 1 to 3 and 60% weightage on modules 4 to 6.

		Walc		of Engineering Autonomous Institut									
				2024-25									
				Information									
Progr	amme		B.Tech. (Electron										
	Semester		Final Year B. Tec										
Cours	Course Code Course Name Course Name Course Name Course Name Professional Elective V- Pattern Recognition and Application												
Cours													
Desire	esired Requisites: Basics of linear Algebra, Image processing/ Computer Vision												
	Teaching	Scheme		Examination S	cheme (Marks)								
Lectu	re	3 Hrs/week	MSE	ISE	ESE	Total							
Tutor	ial	-	30	20	50	100							
	Credits: 3												
				Objectives									
1			<u> </u>	of pattern recogniti		•,•							
3					olications in pattern rec								
4	To Explore advanced topics in pattern recognition, such as deep learning and neural r Understand the concept of statistical pattern recognition and its applications.												
-	Chacista			ith Bloom's Taxon									
At the		course, the stud	ents will be able to	,	-								
CO1	To Iden systems.	tify the key co	mponents and pro	ocesses involved in	n pattern recognition	Understand							
CO2		ature extraction in datasets.	and selection meth	ods to effectively r	represent and describe	Apply							
CO3	Analyze	and interpret th	ne results of pattern	recognition algori	thms and models.	Analyze							
Modu				Contents		Hours							
I	Image patter patter	e Fundamentals in recognition, Con recognition p	omponents of Patte	ern Recognition Sys metrics for pattern	efinition and scope of stems, Overview of the recognition systems,	7							
П	Feature Extraction and Selection: Feature representation and feature vectors, Feature extraction techniques (e.g., statistical, frequency domain, transform-based), Dimensionality reduction techniques (e.g., Principal Component Analysis (PCA), Linear Discriminant Analysis (LDA)), Feature selection methods (e.g., Sequential Forward Selection (SFS), Genetic Algorithms).												
III	Bayesian Decision Theory: Introduction to Bayes' theorem, Bayes decision rule and decision boundaries Minimum error rate classification, Classifiers based on Gaussian distributions (e.g., Naive Bayes, Gaussian Mixture Models).												
IV	Linea Neigh Unsu Clust	nbors (k-NN) alg pervised Learn	., Perceptron, Supporthm, Decision ting and Clusterin	ree classifiers. g	es (SVM)), k-Nearest	7							

V	Neural Networks for Pattern Recognition: Introduction to artificial neural networks (ANNs), Perceptrons and multilayer perceptrons (MLPs), Backpropagation algorithm for training ANNs, Convolutional Neural Networks (CNNs) for image recognition, Recurrent Neural Networks (RNNs) for sequence data.	6
VI	Statistical Pattern Recognition: Maximum Likelihood Estimation (MLE) and Maximum a Posteriori (MAP) estimation, Hidden Markov Models (HMMs) for sequential data, Gaussian Mixture Models (GMMs), Expectation-Maximization (EM) algorithm.	6
	Textbooks	
		and Machine
1	Milan Sonka, Vaclav Hlavac, and Roger Boyle, "Image Processing, Analysis, a Vision"	and Machine
2	Christopher M. Bishop, "Pattern Recognition and Machine Learning",2006	
3	Sergios Theodoridis and Konstantinos Koutroumbas, "Introduction to Pattern Re MATLAB Approach"	cognition: A
4	Richard O. Duda, Peter E. Hart, and David G. Stork, "Pattern Classification"	
	References	
1	R. Schalkoff, Pattern Recognition - Statistiucal, Structural and Neural Appro Wiley, 1992.	aches, John
2	J.I. Tou & R.C. Gonzalez, Pattern Recognition Priciples, Addition-Wesley.	
	· · · · · · · · · · · · · · · · · · ·	
	Useful Links	
1	https://www.coursera.org/learn/pattern-recognition-machine-learning	
2	https://www.springer.com/gp/book/9780387310732	
3	https://www.journals.elsevier.com/pattern-recognition	
4	https://github.com/	

	CO-PO Mapping													
		Programme Outcomes (PO)												
	1	1 2 3 4 5 6 7 8 9 10 11 12												
CO1	2													
CO2		2												
CO3												2		

Assessment

The assessment is based on MSE, ISE and ESE.

MSE shall be typically on modules 1 to 3.

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ESE shall be on all modules with around 40% weightage on modules 1 to 3 and 60% weightage on modules 4 to 6.

		Walc	hand College	of Engineerin					
			,	2024-25					
			Course 1	Information					
Progr	amme	2	B.Tech. (Electron	nics Engineering)					
Class,			Final Year B. Tea						
Cours	se Cod	le	6EN413						
Cours	se Nan	ne	Professional Elec	tive V - Advanced	d Control Systems				
Desire	ed Rec	quisites:	Embedded Syster	n Design, FPGA l	Based System Design				
	Teacl	hing Scheme		Examination	Scheme (Marks)				
Lectu	re	3 Hrs/week	MSE	ISE	ESE	Total			
Tutor	ial	-	30	20	50	100			
				Cre	dits: 3				
				Objectives					
1	cont	rollability and observ	ability.		tability analysis. Inclu	ding			
2	It al	so deals with digital		•					
A + +ba	and a		Outcomes (CO) w		onomy Level				
CO1	_	f the course, the studerstand state space,			nalveie Including				
		rollability and observ	_	m, and stability a	marysis. Including	Understand			
CO2	App	oly and Analyze cond	cepts of digital con	trol devices, syste	ms and algorithms.	Apply, Analyze			
CO3	Stab	oility Analysis using o	different technique	s.		Analyze			
Modu	ıle		Module	Contents		Hours			
		State Snace Analysis							
I	State Space Analysis: Multivariable systems, State Space Representation of systems, Solution of State Equation, State Transition Matrix, Transfer function from state variablemodel, Eigenvalues and Eigenvectors, Concepts of controllability and observability, Tests for controllability and observability for continuous time systems – Time varying case, minimum energy control, time invariant case, Principle of Duality, Controllability and observability form Jordan canonical forms.								
II	hysteresis & dead zone, saturation/coulomb friction & backlash.								
III	i	•	Direct method of		bility and Lypanov's Linear and Nonlinea	_			

IV	Digital Control Introduction: Why Use Digital Control, Configuration of the Basic Digital Control Scheme, Principles of Signal Conversion, Basic Discrete – Time signals, Time –Domain models for discrete – time systems, Transfer function models, Stability on the Z-plane and the Jury stability criterion, Sampling as Impulse Modulation, Sampled Spectra and Aliasing, Filtering Practical Aspects of thechoice of sampling rate, Principle of discretization, The Routh stability criterion on the r-plane.	7
V	Digital Control Devices and Systems and Algorithms: Introduction, z-Domain description of sampled continuous – time plants, z-Domain description of systems with Dead – Time, Implementation of Digital Controllers, Digital temperature control system, Digital position control system, Stepping motors and their control. z- plane specifications of control system design, Digital compensator Design using frequency response plots, Digital compensator Design using root Locus plots, z- plane Synthesis.	7
VI	Pole-placement Design and State observers: Introduction, Stability improvement by state feedback, Necessary and sufficient conditions of arbitrary pole-placement, State regulator design, Design of State Observers, Compensator Design by the separation principle, Servo design: Introduction of the reference input by feed forward control, StateFeedback with Integral Control, Digital Control systems with state feedback, Deadbeat control by state feedback and Dead beat observers.	6
	Textbooks	
1	Modern Control System Theory – by M. Gopal, New Age International Publishers, 1996.	2nd edition
	References	
1	"Modern Control Engineering" – by K. Ogata, Prentice Hall of India, 3rd edition, 1	998
	"Control Systems Engineering" by I.J. Nagarath and M.Gopal, New Age Internation	
2	Ltd.	
3		ompanies,

	CO-PO Mapping													
		Programme Outcomes (PO) PSO												
	1	1 2 3 4 5 6 7 8 9 10 11 12 1 2												
CO1	2	2												
CO2		2												2
CO3	CO3 2													
	1: Low, 2: Medium, 3: High													

		W	Talchand College of (Government Aided Au		angli					
			AY 202	24-25						
			Course Info	ormation						
Programme B.Tech. (Electronics Engineering) Class Semester Final Year B. Tech. Sem. VII										
Class,	Class, Semester Final Year B. Tech. Sem. VII Course Code 6EN414									
Cours	e Cod	e	6EN414							
Cours	e Nam	ie	Professional Elective VI	- Internet of Things						
Desire	ed Req	uisites:	Sensors and Instrumenta	tion, Embedded Sys	stem					
To	eachin	g Scheme	Ex	xamination Scheme	e (Marks)					
Lectu	Lecture 3 Hrs/week MSE ISE ESE									
Tutorial - 30 20 50										
Practi	cal	-								
Intera	ction	-		Credits: 3						
		1								
			Course Ob	ojectives						
1	To p	ovide understa	nding of the Internet of Th	ings concepts.						
2			ous IoT communication pr							
3	To u		cations of Internet of Thing							
			rrse Outcomes (CO) with	Bloom's Taxonom	ıy Level					
			students will be able to,			YY 1 . 1				
CO1		ain IoT building		-1		Understand				
CO2			Γ connectivity and commu		es	Analyze				
<u> </u>	Desi	gn applications	for solution building in Io	1 domain		Apply				
Modu	ıla		Module Co	44		TTowns				
Modu		- T. F 1 4		ntents		Hours				
Τ			als and Overview: Characteristics of IoT, Ph	visical Design of I	oT IoT anablad	6				
I			oT Applications: Smart cit	•		6				
		mart Energy, Si		ics, Smart Homes,	mart Agriculture,					
			evices and Endpoints:							
II Mobile Ad hoc Network, Stationary and Mobile Wireless Sensor Networks,										
	H	lardware and s	oftware architecture of se	ensor node ,type of	sinks, gateway,					
		perating systen								
			ork layer for sensor netw							
III			Protocols for sensor netw		n, low duty cycle	8				
			ake up concepts for energy	conservation						
IV	N		ation Technologies: for IoT- 6LowPAN, RFI	D, Wireless HART	, MQTT, CoAP,	6				

V	Cloud and SDN: cloud computing and virtualization concepts, Cloud Architecture, Cloud computing, benefits, challenges, risksCloud services, introduction to software defined network	6					
VI	IoT Security and Authentication:						
	Text Books						
1	Sudip Misra, Chandana Roy, Anandarup Mukherjee, "Introduction to Industrial Internand Industry 4.0" 2021	net of Things					
	D.f						
1	References N. H. H. (PH)						
1	D.E. Comer "Internetworking with TCP/IP", Vol. I (4th Edition), II, III (PHI)						
2	Olivier Hersent, David Boswarthick "Internet of Things Applications and Protocols publication 2nd Ed.	", Wiely					
3	William Stallings "Foundations of Modern Networking: SDN, NFV, QoE, IoT and Clo Education	oud" Pearson					
	Useful Links						
1	https://onlinecourses.nptel.ac.in/noc21_cs17/preview						

	CO-PO Mapping														
		Programme Outcomes (PO)												PSO	
	1	2	3	4	5	6	7	8	9	10	11	12	1	2	
CO1			3						3				2		
CO2			3											2	
CO3	2													3	
CO4															

Assessment

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MSE shall be typically on modules 1 to 3.

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ESE shall be on all modules with around 40% weightage on modules 1 to 3 and 60% weightage on modules 4 to 6.

		Walc	hand College (of Engineering Autonomous Institut					
			· · · · · · · · · · · · · · · · · · ·	2024-25					
				Information					
Progra	amme		B.Tech. (Electron	nics Engineering)					
Class, Semester Final Year B. Tech., Sem. VII									
Course Code 6EN415									
Course Name Professional Elective VI- Machine Learning									
Desired Requisites: Basics of linear algebra, Probability and statistics									
		ng Scheme		Examination S					
Lectur		3 Hrs/week	MSE	ISE	ESE	Total			
Tutori	ial	-	30	20	50	100			
				Cred	its: 3				
			~						
1	T	1		Objectives (MI)					
2			of Machine Learniques and Learning						
3			mentation aspects						
4			Advanced Topics in		<u> </u>				
			Outcomes (CO) w						
			ents will be able to						
CO1			l and basics of Mac			Understand			
CO2	I	_		•	in implementing and				
		ing machine learn works	ing algorithms usi	ng popular progra	mming libraries and	Apply			
CO3			ving machine learni	ng techniques to re	al-world datasets and				
	probl			8 1 1		Apply			
CO4	Stay	Jpdated with Recei	nt Developments an	d advancements in	machine learning.	Analyse			
Modu			Module	Contents		Hours			
		troduction to Mac	0	T	1				
I			of machine learnin						
1		(supervised, unsupervised, reinforcement learning), Key applications of machine learning, Overview of the machine learning process, Linearity and Non linearity							
			Machine learning – Data Understanding Representation and						
	vi	sualization.							
		pervised Learnin		. 1 .	• .•				
11		Linear regression and regularization techniques, Logistic regression for classification, k-Nearest Neighbors (k-NN) algorithm, Decision trees and							
II					Decision trees and port Vector Machines				
			etrics for classifica						
	U	supervised Learn	ing Algorithms:						
III	III Clustering algorithms (k-means, hierarchical clustering), Dimensionality								
	reduction techniques (Principal Component Analysis (PCA), Anomaly detection,								
			r unsupervised lear	ning tasks.					
			d Deep Learning:	rks Activation fu	nctions and gradien	f			
IV					ation, Convolutiona				
					ent Neural Networks				
				on to deep learning	ng frameworks (e.g.	,			
	⊥ T	nsorFlow, PyTorcl	1).						

	Model Evaluation and Selection:					
	Training set, validation set, and test set, Cross-validation techniques, Bias-					
V	variance trade off, Overfitting and underfitting, Hyperparameter tuning and model	7				
	selection, Model interpretation.					
	Optimization Methods: Optimization Methods: Gradient descent, stochastic					
	gradient descent (SGD) and extensions to SGD, regularization					
	Advanced Topics in Machine Learning:					
VI	Ensemble methods (e.g., bagging, boosting), Reinforcement learning basics	5				
	Introduction to natural language processing (NLP), Time series analysis and					
	forecasting, Transfer learning and domain adaptation					
	Textbooks					
1	Christopher M. Bishop, "Pattern Recognition and Machine Learning",2006					
2						
2	Shai Shalev-Shwartz and Shai Ben-David. Understanding Machine Learning: Fro	om Theory to				
3	Algorithms. Cambridge University Press. 2014.					
4	Ian Goodfellow, "Deep Learning", Yoshua Bengio, and Aaron Courville					
	References					
1	Trevor Hastie, Robert Tibshirani, and Jerome Friedman, "The Elements of Statistic	cal Learning"				
2	Kevin P. Murphy, "Machine Learning: A Probabilistic Perspective"					
3	Aurélien Géron, "Hands-On Machine Learning with Scikit-Learn, Keras, and Tens	sorFlow"				
	Useful Links					
1	https://www.kaggle.com/					
2	https://scikit-learn.org/stable/documentation.html					
3	https://www.tensorflow.org/learn					
4	https://www.coursera.org/					

CO-PO Mapping													
	Programme Outcomes (PO) PSO												
1	2 3 4 5 6 7 8 9 10 11 12 1 2												
2													
	2												
			2										
											2		
				1 2 3 4 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2	Progra: 1 2 3 4 5 2 2 2 2	Programme O 1 2 3 4 5 6 2 2 2 2 2	Programme Outcom 1 2 3 4 5 6 7 2 2 2 2 2 2	Programme Outcomes (PO 1 2 3 4 5 6 7 8 2 2 2 3 4 5 6 7 8 2 2 3 4 5 6 7 8	Programme Outcomes (PO) 1 2 3 4 5 6 7 8 9 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2	Programme Outcomes (PO) 1 2 3 4 5 6 7 8 9 10 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2	Programme Outcomes (PO) 1 2 3 4 5 6 7 8 9 10 11 2 2 3 4 5 6 7 8 9 10 11 2 3 4 5 6 7 8 9 10 11 2 3 4 5 6 7 8 9 10 11 2 3 4 5 6 7 8 9 10 11 2 3 4 5 6 7 8 9 10 11 2 4 5 6 7 8 9 10 11	Programme Outcomes (PO) 1 2 3 4 5 6 7 8 9 10 11 12 2 2 3 4 5 6 7 8 9 10 11 12 2 3 4 5 6 7 8 9 10 11 12 2 3 4 5 6 7 8 9 10 11 12 3 4 5 6 7 8 9 10 11 12 4 5 6 7 8 9 10 11 12 2 4 5 6 7 8 9 10 11 12 3 4 5 6 7 8 9 10 11 12 4 5 6 7 8 9 10 11 12 <th>Programme Outcomes (PO) PS 1 2 3 4 5 6 7 8 9 10 11 12 1 2 2 3 4 5 6 7 8 9 10 11 12 1 2 3 4 5 6 7 8 9 10 11 12 1 2 3 4 5 6 7 8 9 10 11 12 1 2 3 4 5 6 7 8 9 10 11 12 1 2 3 4 5 6 7 8 9 10 11 12 1 3 4 5 6 7 8 9 10 11 12 1 4 5 6 7 8 9 10 11</th>	Programme Outcomes (PO) PS 1 2 3 4 5 6 7 8 9 10 11 12 1 2 2 3 4 5 6 7 8 9 10 11 12 1 2 3 4 5 6 7 8 9 10 11 12 1 2 3 4 5 6 7 8 9 10 11 12 1 2 3 4 5 6 7 8 9 10 11 12 1 2 3 4 5 6 7 8 9 10 11 12 1 3 4 5 6 7 8 9 10 11 12 1 4 5 6 7 8 9 10 11

Assessment

The assessment is based on MSE, ISE and ESE.

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Walchand College of Engineering, Sangli (Government Aided Autonomous Institute) AY 2024-25 Course Information Programme B. Tech. (Electronics Engineering) Class, Semester Final Year B. Tech., Sem. VII Course Code 6EN416 **Course Name** Professional Elective VI - Analog CMOS IC Design Digital Electronics, Digital CMOS IC Design **Desired Requisites: Teaching Scheme Examination Scheme (Marks)** Lecture 3 Hrs/week **MSE** ISE ESE Total Tutorial 30 20 50 100 **Practical** Interaction Credits: 3 **Course Objectives** To explain the analog circuit concepts based on MOS devices in such a way to develop in 1 students the insight and intuition towards MOS circuits. 2 To **organize** guest lectures and practical sessions with the help of industry persons. To **deliver** the tips (or thumb rules) related with design of analog circuits throughout the course. 3 To **motivate** the students to develop lifelong/ self-learning attitude. 4 Course Outcomes (CO) with Bloom's Taxonomy Level At the end of the course, the students will be able to, Analyze MOS device circuits to derive the dependence of various electrical Analyze parameters analytically and graphically. (M1) Develop large signal and small signal models for single stage amplifiers and Apply CO₂ differential amplifiers using MOS transistors and derive the gain relationships. (M2, Design common source, common gate, common drain amplifier for given Design **CO3** specifications. Further recognize their application under various typical situations. Analyze large signal and small signal behaviour of differential amplifiers and compute Analyze **CO4** the differential gain, common mode gain and CMRR. (M3) Analyze active current mirrors and explain the properties of differential pairs using **CO5** Analyze such circuits as loads. (M5) **CO6 Design** 2-stage Op-Amp for given specifications. **Compute** the poles and zeros in the Design frequency response of the single stage amplifiers using time-constant method (M6) Module **Module Contents** Hours **MOS Device Physics:** MOS IV Characteristics. Second Order Effects, MOS device models (MOS device I 8 capacitance, MOS small signal model) MOS model parameters **Single Stage Amplifier:** II Part I CS stage with resistance load, diode connected load, current source load, 6 CS stage with source, degeneration, Single Stage Amplifier: Ш Part II source follower, common-gate stage, Cascade stage, folded cascade, choice 6 of device models. **Differential Amplifiers:** Basic difference pair, differential mode response, common mode response, IV 6 Differential pair with MOS loads **Passive and Active Current mirrors:** Basic current mirrors, Cascade mirrors, active current mirrors. 7 **Frequency Response:** VI CS stage, Source follower, Common gate stage, Cascade stage and Difference pair. 7 Design of 2-stage operational amplifier

	Text Books						
Behzad Razavi, "Design of Analog CMOS Integrated Circuits", Second Edition, Tata M							
1	Hill Publishing Company Limited, New Delhi, 2017.						
	References						
1	R. Jacob Baker, "CMOS: Circuit Design, Layout and Simulation", Wiley-Inter-science, (2008)						
2	Allen, P.E. and Holberg, D.R., "CMOS Analog Circuit Design", Oxford University Press (2002)						
	Useful Links						
1	www.vlsi-expert.com,						
2	www.testbench.in						
3	www.asic-world.com						
4	https://nptel.ac.in/courses/117/101/117101105/						

	CO-PO Mapping														
		Programme Outcomes (PO)											PS	PSO	
	1	2	3	4	5	6	7	8	9	10	11	12	1	2	
CO1	2	3												3	
CO2	2	3												3	
CO3			3											3	
CO4	2	3												3	
CO5	2	3												3	
CO6		2	3											3	

Assessment

The assessment is based on MSE, ISE and ESE.

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ESE shall be on all modules with around 40% weightage on modules 1 to 3 and 60% weightage on modules 4 to 6.

Walchand College of Engineering, Sangli

(Government Aided Autonomous Institute)

AY 2024-25

Course	Inform	otion
Course	HUIOTH	ialion

	Course information	
Programme	B.Tech. (Electronics Engineering)	
Class, Semester	Final Year B. Tech., Sem. VII	
Course Code	6EN453	
Course Name	Professional Elective V -Internet of Things Lab	
Desired Requisites:	Sensors and Instrumentation, Embedded System	

Teaching	Scheme		Examination Scheme (Marks)							
Practical	2 Hrs/ Week	LA1	LA2	Lab ESE	Total					
Interaction	- Hrs/ Week	30	30	40	100					
			Cree	dits: 1						

Course Objectives

- 1 To provide understanding of the Internet of Things concepts.
- 2 To demonstrate sensor node architecture and communication.
- 3 To understand applications of Internet of Things and its usefulness for society.

Course Outcomes (CO) with Bloom's Taxonomy Level

At the end of the course, the students will be able to,

CO1	Design sensor node	Apply
CO2	Compare various connectivity and communication technologies	Analyze
CO3	Simulate/Design applications for solution building in IoT domain	Create

List of Experiments / Lab Activities/Topics

List of Lab Activities:

- 1. Introduction to IoT Devices: Arduino, Raspberry Pi, Node-MCU, etc.
- 2. Sensor Interfacing:

Different sensors with IoT devices.

Collecting sensor data and displaying it on the device

3. Actuator Control:

1

Controlling actuators using IoT devices.

4. Data Logging and Visualization:

Logging sensor data on IoT devices or cloud platforms. sensor data using graphs or web interfaces

- 5. IoT Security and Authentication:
- 6. IoT Energy Management: Optimizing power consumption through sleep modes, duty cycling, and low-power components, Implementing basic security measures for IoT devices
- 7. Use of IoT public cloud for data storage and processing
- 8. All above experiments design and simulate using appropriate tools.

Textbooks

"Introduction to Industrial Internet of Things and Industry 4.0" Sudip Misra, Chandana Roy, Anandarup Mukherjee 2021

References

1	"Internet of Things Applications and Protocols", Wiely publication 2nd Ed.								
2	William Stallings "Foundations of Modern Networking: SDN, NFV, QoE, IoT and Cloud"								
	Pearson Education								
	Useful Links								
1	-								

						CO-P	О Мар	ping						
		Programme Outcomes (PO)											PS	SO
	1	2	3	4	5	6	7	8	9	10	11	12	1	2
CO1			3											2
CO2				3										
CO3					3				3				2	
CO4														

Assessment

There are three components of lab assessment, LA1, LA2 and Lab ESE.

IMP: Lab ESE is a separate head of passing.(min 40 %), LA1+LA2 should be min 40%

Assessment	Based on	Conducted by	Typical Schedule	Marks
LA1	Lab activities, attendance, journal	Lab Course Faculty	During Week 1 to Week 8 Marks Submission at the end of Week 8	30
LA2	Lab activities, attendance, journal	Lab Course Faculty	During Week 9 to Week 16 Marks Submission at the end of Week 16	30
Lab ESE	Lab activities, journal/ performance	Lab Course Faculty and External Examiner as applicable	During Week 18 to Week 19 Marks Submission at the end of Week 19	40

Walchand College of Engineering, Sangli

(Government Aided Autonomous Institute)

AY 2022-23

	A 1 2022-25							
Course Information								
Programme B.Tech. (Electronics Engineering)								
Class, Semester	Final Year B. Tech., Sem. VII							
Course Code	6EN454							
Course Name	Professional Elective VI-Machine Learning lab							
Desired Requisites:	Python Programming							

Teachir	ng Scheme	Examination Scheme (Marks)							
Practical	2 Hrs/ Week	LA1	LA2	Lab ESE	Total				
Interaction -		30	30	40	100				
			Credits: 1						

	Course Objectives							
1	To make students do practical implementation of the different ML concepts and techniques.							
2	To make students familiar with steps involved in applying machine learning algorithms to real-life Problems							
3	Make use of Data sets in implementing the machine learning algorithms.							
4	To develop research interest towards this field.							
	Course Outcomes (CO) with Bloom's Taxonomy Level							
At th	e end of the course, the students will be able to,							
CO 1	Apply ML algorithms to solve real world problems and analyze the results.	Apply, Analyze						
CO 2	Design and provide best solution to ML problems by measuring the performance of different algorithms/tools, and comparing them.	Evaluate, Create						

List of Experiments / Lab Activities/Topics

List of Lab Activities:

- 1. Implement a classification algorithm, such as logistic regression or a decision tree with suitable data set from real world problem and classify the data set to produce new sample.
- 2. Build a linear regression model on any dataset with appropriate features and targets.
- 3. Build an SVM model to classify a dataset with multiple classes.
- 4. Implement character recognition using Multilayer Perceptron.
- 5. Implement backpropagation Algorithm for X-OR function.
- 6. Use convolutional neural networks (CNNs) to classify images from suitable dataset.
- 7. Apply clustering algorithms like k-means or hierarchical clustering on appropriate dataset.
- 8. Build an anomaly detection model to identify unusual patterns.

Mini-project: students work in team on any socially relevant problem that needs a machine learning based solution, and evaluate the model performance.

	Textbooks								
1	"Hands-On Machine Learning with Scikit-Learn, Keras, and TensorFlow" by Aurélien Géron								
2	"Python Machine Learning" by Sebastian Raschka and Vahid Mirjalili								
3	"Machine Learning: A Hands-On Approach" by Thomas Dehaene								
4	"Machine Learning for Dummies" by John Paul Mueller and Luca Massaron:								

	References							
1	Practical Machine Learning for Computer Vision" by Martin Görner, Ryan Gillard, and							
1	Valliappa Lakshmanan							
	"Applied Machine Learning: Algorithms and Labs with Python" by Kelleher, Mac Namee, and							
	D'Arcy							
	Useful							
	Links							
1	https://www.kaggle.com/kernels							
2	https://scikit-learn.org/stable/auto_examples/index.html							
3	https://www.tensorflow.org/tutorials							
4	https://www.coursera.org/							

	CO-PO Mapping													
	Programme Outcomes (PO)										PSO			
	1	2	3	4	5	6	7	8	9	10	11	12	1	2
CO1	3													
CO2		2	2		2									

Assessment

There are three components of lab assessment, LA1, LA2 and Lab ESE.

IMP: Lab ESE is a separate head of passing.(min 40 %), LA1+LA2 should be min 40%

Assessment	Based on	Conducted by	Typical Schedule	Marks
LA1	Lab activities, attendance, journal	Lab Course Faculty	During Week 1 to Week 8 Marks Submission at the end of Week 8	30
LA2	Lab activities, attendance, journal	Lab Course Faculty	During Week 9 to Week 16 Marks Submission at the end of Week 16	30
Lab ESE	Lab activities, journal/ performance	Lab Course Faculty and External Examiner as applicable	During Week 18 to Week 19 Marks Submission at the end of Week 19	40

Walchand College of Engineering, Sangli (Government Aided Autonomous Institute) AY 2024-25 **Course Information** B. Tech. (Electronics Engineering) **Programme** Final Year B. Tech., Sem. VII Class, Semester 6EN455 Course Code Course Name Professional Elective VI - Analog CMOS IC Design Lab **Desired Requisites:** Digital Electronics, Digital CMOS IC Design **Teaching Scheme Examination Scheme (Marks)** Practical 2 Hrs/Week LA1 Lab ESE Total 100 Interaction 30 30 40 Credits: 1 **Course Objectives Demonstrate** the flow of Cadence EDA tools for designing and simulating analog CMOS 1 circuits. **Develop** an insight into CMOS analog circuits and design single stage CS, CG, CD, differential 2 amplifiers and 2-stsge Operational amplifier for given specifications. **Explain** how to characterize the transistors for the voltage conditions seen by the circuit with goal 3 of optimizing dimensions for given ID or trans-conductance. 4 **Prepare** the students for good documentation discipline. Course Outcomes (CO) with Bloom's Taxonomy Level At the end of the course, the students will be able to. Analyze MOS transistors for targeted value of g_m or drain current for designing the Analyze **CO1** physical dimensions and the required gate bias using Cadence EDA tools. **Demonstrate** the complete flow of Cadence tools from schematic to symbol Understand CO₂ generation to simulation for CS, CG, CD and differential amplifiers Build and simulate the single stage amplifier circuits (CS, Source Follower, Apply **CO3** Cascode stage, differential pair etc.) using MOSFETs schematic design entry for various loads and relate the gain values with theoretical expressions. **Design** differential pair circuits with active current mirror load for given gain and Create **CO4** UGB.

List of Experiments / Lab Activities/ Topics

Create

Design, build and simulate 2-stage operational amplifier for given pole frequencies

List of Experiments:

CO5

1. Characterize nMOS transistors from schematic using Cadence tools.

and UGB with and without pole splitting and pole-zero compensation.

- 2. Design, build and simulate single stage Common Source amplifier using resistive load and nMOS diode connected load (Gain and Frequency response). Compare the performance with pMOS diode connected load.
- 3. Design, build and simulate Common Source amplifiers with current source load. Compare the performance with already studied loads.
- 4. Design, build and simulate Common Source stage with source degeneration. (gain and frequency response) Compare the performance with and without source degeneration.
- 5. Design, build and simulate Source follower /Common Gate stage. Crosscheck the results of output impedance, gain, power dissipation against theoretical expectations.
- 6. Design, build and simulate cascode stage with different loads for the specified voltage gain and maximum power dissipation.
- 7. Design, build and simulate differential pair with specified tail current source and maximum full swing differential gain using, a)resistive load and b) pMOS current source load and compare the gain values. Cross-confirm the results against theoretical expectations.

- 8. Demonstrate the design of differential pair with active tail current source (replace the tail current source in Expt. 8 by a nMOS current source biased in saturation). Simulate for evaluating differential gain, common mode gain and CMRR.
- 9. Design, build and simulate differential amplifier (single ended output) with active current mirror load for the given specifications. Evaluate for CMRR, DC gain etc.
- 10. Demonstrate design of 2-stage operational amplifier for given UGB.

	Text Books							
1	Behzad Razavi, "Design of Analog CMOS Integrated Circuits", Second Edition, Tata McGraw-Hill Publishing Company Limited, New Delhi, 2017.							
	References							
1	R. Jacob Baker, "CMOS: Circuit Design, Layout and Simulation", Wiley-Inter-science, 2008.							
2	Allen, P.E. and Holberg, D.R., "CMOS Analog Circuit Design", Second Edition, Oxford							
	University Press, 2002.							
	Useful Links							
1	www.vlsi-expert.com							
2	www.testbench.in							
3	www.asic-world.com							
4	https://nptel.ac.in/courses/117/101/117101105/							

	CO-PO Mapping													
		Programme Outcomes (PO)										PS	PSO	
	1	2	3	4	5	6	7	8	9	10	11	12	1	2
CO1	1			2	3									3
CO2				2	3									3
CO3			2	2	3									3
CO4				3	3									3
CO5				3	3									3

Assessment

There are three components of lab assessment, LA1, LA2 and Lab ESE.

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LAI	attendance, journal	Faculty	Marks Submission at the end of Week 8	30
LA2	Lab activities,	Lab Course	During Week 9 to Week 16	30
LAZ	attendance, journal	Faculty	Marks Submission at the end of Week 16	30
		Lab Course	During Week 18 to Week 19	
	Lab activities,	Faculty and	Marks Submission at the end of Week 19	
Lab ESE	journal/	External		40
	performance	Examiner as		
		applicable		

		Walc	hand College (Government Aidea				
			·	2024-25	iie)		
			Course 1	Information			
Progra	amn	ne	B.Tech. (Electror	nics Engineering)			
Class, Semester Final Year B. Tech., Sem. VII							
Course Code 6OE457							
Cours	e Na	nme	Open Elective III	-Medical Image I	Processing		
Desire	ed R	equisites:	Signal Processing				
	Tea	ching Scheme		Examination	Scheme (Marks)		
Lectur		3 Hrs/week	MSE	ISE	ESE	T	otal
Tutori	ial	0 Hrs/week	30	20	50	1	100
				Cre	edits: 3	ı	
		'	1				
			Course	Objectives			
1	То	learn facts about med	ical imaging source	es and study vario	ous formats.		
2	_	study various segmen			lical image.		
3	То	learn spatial transform					
A1	1		Outcomes (CO) w		onomy Level		
	_	of the course, the stud			and		
CO1		monstrate various im age.	lage sources, there	e representation	and various formats	SOI	II
CO2	Ap	ply segmentation, filte	ering and transform	nation on medical	image.		IV
CO3	An	alyze various facts of	image registration	and CT reconstru	cted image.		IV
Mada	la		Madula	e Contents			II
Modu	iie	D		Contents			Hours
I		Basics of Medical In Radiology, the elect imaging, computed nuclear medicine an protection and dosime	romagnetic spectro tomography, mag d molecular imag	netic resonance	tomography, ultraso	ound,	7
II	Image Representation: Pixels and voxels, gray scale and color representation, image file formats, DICOM,						
III		Image segmentation Region growing, k-m functions, multi-atlas	eans clustering, sr		n to level sets,speed		7
IV		Image enhancement contrast enhancement Fourier theory, anisot	t, denoising, debl	urring, edge dete	ection, derivativesar	nd	6

	Image registration:								
	correlation, least squares, transform based registration, joint entropy, mutual	6							
V	information, binning discontinuities, registration optimization, registration by								
	clustering, ensemble registration, gaussian mixture models.								
VI	Medical image reconstruction:	6							
V 1	Theory of MRI reconstruction, MRI motion, compensation, algebraic CT								
	reconstruction, CT filtered back-projection.								
	Textbooks								
1	Prince J L and Links J M, Medical Imaging Signals and Systems, Pearson (2015).								
2	Suetens P, Fundamentals of Medical Imaging, Cambridge University Press (2009).								
	References								
	Birkfellner W, Applied Medical Image Processing: A Basic Course, CRC Press								
1	(2014).								
	Nishimura D, Principles of Magnetic Resonance Imaging, Stanford University								
2	Press (2010).								
	Useful Links								
1	https://onlinecourses.nptel.ac.in/noc22_ee64/preview								

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	Programme Outcomes (PO)												PSO	
	1	2	3	4	5	6	7	8	9	10	11	12	1	2
CO1	3													
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CO3				3										
CO4				3										

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